## **Transducers and sensors**

#### •All instruments based on measuring signals

therefore need to understand the types of signals properties and characteristics of transducers applications which are appropriate impact on the instrument systems

#### •Transducer

devices which produce an electrical signal proportional to a variable of interest why? automation for speed, convenience (eg alarm) or objectivity ease further manipulation of measurements extend range of processing beyond simple calculations digital processing now very cheap

•Big area - so which transducers should interest us most? Try to find: examples of components used for control or monitoring purposes sensors which exhibit properties of general interest, even if employed for special purposes (like physics research...)

1

## **Major transducer types**

#### •Control or measurement

temperature, pressure, humidity, B-field, sound, strain, acceleration,...

growing area of bio-chemical sensors

beyond scope of these lectures but many common principles electrical output often desirable for reasons already cited

#### •ionisation sensors

general purpose light detection (especially optical communication), radiation detection ( $\alpha$ ,  $\beta$ ,  $\gamma$ , x-ray, charged particle,...) many examples of sensors developed for physics which now form components for general use

and vice-versa specialised state of art instruments often exploit new technologies

## **Equivalent circuits**

- •To use any device, we need an effective model of it should characterise important properties
- •Most common & simple picture

Voltage source

with associated impedance

Current source

this defines how to connect it to a useful circuit

## Voltage source

 $i = V_{source} / (R_{source} + R_{load})$  $V_{load} = iR_{load} = V_{source} R_{load} / (R_{source} + R_{load})$ 

if 
$$R_{source} \gg R_{load}$$
  $V_{load} \ll V_{source}$ 

if 
$$R_{source} \ll R_{load}$$
  $V_{load} \approx V_{source}$ 



we can only sometimes choose  $\mathbf{R}_{\mathrm{source}}$ 

usually defined by transducer - may influence transducer selection but often transducer chosen first

we do not always have complete freedom over  $\boldsymbol{R}_{\text{load}}$ 

eg if long cables are required

•To measure voltages, will often require a high load impedance

or low source impedance, if intervening circuit

•Matching

if  $R_{load} = R_{source}$  obtain maximum power transfer from source to load then  $V_{load} = V_{source}/2$ 

4

### **Current source**

$$V_{load} = I_{source}(R_{source} | | R_{load}) = I_{source}R_{source}R_{load} / (R_{source} + R_{load})$$

$$I_{load} = I_{source}R_{source} / (R_{source} + R_{load})$$

$$if R_{load} \ll R_{source} I_{load} \approx I_{source}$$

$$R_{source} = I_{source} R_{source} I_{load} \approx I_{source}$$

same comments as previous about ability to choose  $R_{\rm source}$  and  $R_{\rm load}$ 

•To measure currents, will usually require a low load impedance or high (parallel) source impedance, if intervening circuit

#### •Matching

 $R_{load} = R_{source}$  to obtain maximum power transfer from source to load but this is not always done for practical reasons - discuss later

•Should note that neither source nor load impedance is always simple resistance

### **Temperature measurement**

# Traditional - mercury thermometer need long, accurately dimensioned tube calibrated scale *eg ice, steam*What limits precision? (problem sheet) accuracy of tube bore practical length of accurate tube operating temperature (melting point of glass?) change in metal dimensions & ability to observe them change in dimensions of tube with temperature

### •Although well developed technology, not very practical for many applications

especially those requiring automation & control cheap, accurate digital thermometers now seem to be widely used in hospitals & for home use - not all electronic

•Similar discussion for bi-metallic thermostat

several electronic alternatives are available

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## **Temperature sensor - characteristics required**

•Specifications include

Accuracy

probably will depend on T, precision will depend on application, but should be known

Linearity

```
output (voltage or whatever..) should be \alpha T (K, °C, T-T<sub>0</sub>,..)
```

Interchangeability

```
would like to be able to replace the sensor and get similar results
```

Signal size

ease of measurement

Remote sensing

```
typically sensor can't be right at source, especially if hot or cold
```

Temperature range

specs are unlikely to be met from OK to  $\infty$ 

Cost

•even if we think of a medical thermometer, these requirements do not change much

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## Thermocouple

•junction between two different metals can produce a small voltage

value typically very small (10-100µV/°C)
 depends approximately on difference
 between two junction temperatures
 - one should be reference

#### physics of thermocouple

hot wire end produces a temperature gradient

so a carrier density gradient equilibrium is established when an electric field in the wire balances the carrier diffusion not practical to put voltmeter across ends of wire - could be hot!

well known properties -

so can choose type appropriate to requirement and interchangeable very convenient for quick, simple measurements eg control applications

#### Caveats

relative measurements excellent but absolute measurements need care define reference point ( & maintain constant!)

# **Types of thermocouple (ii)**

#### •www.isi-seal.com/Technical\_Info/ Tech\_Thermocouple.htm



# **Types of thermocouple**

Туре	Metal- 1	Metal- 2	Tmax	Sensitivity	Vout (mV)	Vout (mV)	Vout (mV)	Rlead
			degC	µV/degC	mV	mV	mV	/m
				at 20degC	reference junction at OdegC			typical
					(100 degC) (400 degC)		(1000 degC)	)
т	Inon	Constanton	760	E1 E	E 97	91.95		10
J		Constantan	760	51.5	5.27	21.80		12
K	Chromel	Alumel	1370	40.3	4.10	16.40	41.27	20
Т	Copper	Constantan	400	40.3	4.28	20.87		10
Ε	Chromel	Constantan	1000	60.5	6.32	28.94	76.36	24
S	Platinum	90%Pt-10%Rh	1750	5.9	0.65	3.26	9.59	6
R	Platinum	87%Pt-13%Rh	1750	5.8	0.65	3.41	10.50	6
B	94%Pt-6%Rh	70%Pt-30%Rh	1800	0.0	0.03	0.79	4.83	6
С	95%W-6%Rh	74%W-26%Rh	2320	25.7	2.5	10.0	25.7	
	Constantan	55%Cu- 45%Ni						
	Chromel	90%Ni- 10%Cr						

#### •Junctions are welded by manufacturer

Often equipped to plug into digital volt meter

reference to room temperature with internal circuitry

"home-made" systems need care in adding wires -can add another junction

### 

however, not practical to place integrated circuit at hot node!

### practical issues

low output voltage to be measured eg 20K x 50μV/K = 1mV measuring amplifier needs careful design to avoid noise amplifier input resistance should be reasonably high lead resistance not negligible if long



11

### **Thermistor**

•Semiconductor device with well defined R-T characteristic

coefficient of R vs T ~  $-4\%/^{\circ}$ C ie.  $R/R = \alpha T$  $R_{typical} \sim k\Omega$ precise conformity to standard from manufacturers range ~  $-50^{\circ}C$  to  $+300^{\circ}C$ 

easy to use, with large change in value with temperature

Practical issues

provide current source to operate accuracy depends on application non-linear R-T behaviour accurate applications => careful circuit choice (eg balancing bridge) circuit self-heating can influence small T - thermal noise could be concern need calibration



## **Temperature ICs**

### •Band-gap circuits

Based on semiconductor junction diode  $I \sim exp(qV/kT)$ 

### •eg AD590 - discuss more later

Manufacturer's specs (read them!!)

Two terminal sensor ( $V_{supply}$ : +4V to +30V)

Linear output current  $1\mu A/K$  ,  $\pm 0.3^\circ C$  over range

T range -55°C to +150°C

Calibrated, with accuracy  $\pm 0.5^{\circ}C$ 

Can be used remotely (x100 feet!), with long wires

J

K

L

Μ

Absolute

 $\pm 5.0$ 

 $\pm 2.5$ 

±1.0

 $\pm 0.5$ 

error

Non-

linearity

+1.5

±0.8

±0.4

±0.3

Low cost (£10 for <25) NB several versions

### •Custom ICs -

can design reference circuits,

eg to save space or remote locations





### **Platinum resistance**

#### •Platinum resistance

Very stable and reproducible, wide T range (~ -200°C to 1000°C)

T coefficient ~+0.4%/°C

Bulky and expensive for some applications (~  $\pounds$ 2-3) need wires (R) or local I/V circuit

•Standard value R = 100 (PT100)

eg Pt film deposited on ceramic substrate, laser trimmed for precision

also wirewound versions	Length Width					
	Model	W x L x H (mm)	Туре	Temperature Range	Maximum Current	List Price Class B
	TF-25-100	2.0 x 5.0 x 1.1	PT100	-50 to +650 °C	2 mA	£2.99
	TF-1632-100	1.6 x 3.2 x 1.1	PT100	-50 to +650 °C	1 mA	£2.99
	TF-210-1000	2.0 x 10 x 1.1	PT1000	-50 to +650 °C	1 mA	£3.34
og http://www.kalostoad.o	TF-25-1000	2.0 x 5.0 x 1.1	PT1000	-50 to +650 °C	1 mA	£3.68
eg nup.//www.kalestead.c	o.uk/ tempi					
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### **Other temperature transducers**

•Exotics each a specialised subject

Non-contact measurements infra-red sensors based on, eg, CCDs

Ultra-low temperature ~ OK

### **Ionisation sensors**

#### •Indirect

produce a signal which must be further converted to an electrical signal *mostly light: scintillators, Cerenkov radiation, transition radiation (x-ray) acoustic* 

#### •Direct

produce a directly measurable electrical signal
 may still require amplification
gaseous and semiconductor devices dominate

## **Scintillators**

•Light emitted following ionisation in a transparent material Typical I(t) ~ I<sub>0</sub>e<sup>-t/</sup> sometimes several components I<sub>1</sub>, I<sub>2</sub>,... <sub>1</sub>, <sub>2</sub>,... Wavelength of emission determines requirement on photosensor type along with signal speed requirement

> eg. >  $\mu$ s => count rates  $\ll$  MHz ~ ns => count rates  $\gg$  MHz

•Two main material types - contrasting mechanisms Inorganic scintillators

result of crystalline structure of material

large band gap => insulators

Organic scintillators

molecular property (independent of state - liquid or solid)

# **Inorganic scintillators**

•ionisation excites electrons from valence to conduction band

de-excitation via photon emission or radiationless transition

•Large band gap => slow process low transition probability short wavelength (E = E<sub>bandgap</sub>)

•Impurities add centres (traps) in band-gap increase transition rates suitable doping can also increase light output *eg thallium in NaI* holes trapped at activator sites *recombination with e<sup>-</sup> => photon* smaller energy gap increases wavelength *crystal also transparent to scintillation photons* 



## **Inorganic scintillator characteristics**

•high light output but relatively slow (~µsec), good linearity dense, high atomic number (Z) material good for for e-/gamma ray detection expensive - very good crystals required, usually large. raw material, growing, cutting and polishing of large crystals many require specialised photosensor blue or UV emission some undoped materials offer advantages of speed and radiation hardness drawback of lower light yield care is needed in material preparation performance can be badly affected by (wrong!) impurities some crystals can be coated on photosensors convenient for efficient sensor systems but limits thickness

#### •applications

medical imaging (eg. gamma camera, ~MeV photons from radio-isotopes) astronomy and particle physics detectors

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# **Examples of inorganic scintillators**

		peak	relative	time	Density	, ,
		(nm)	ngne ouepue	(µsec)	g.cm	
Sodium iodide	NaI (Tl)	410	1	0.23	3.7	High light output, hygroscopic, large crystals fragile
Caesium iodide	CsI (Tl)	540	1.71	0.68 (64%) 3.34 (36%)	4.5	Non hygroscopic. wavelength match Si photodiodes
Bismuth germanate	BGO Bi <sub>4</sub> Ge <sub>3</sub> O <sub>12</sub>	480	0.22	0.3	7.1	High Z, low light output
Barium	BaF <sub>2</sub> (fast)	220	0.05	0.0006	4.9	Fast, two components, in UV
fluoride	$BaF_2$ (slow)	310	0.16	0.62		low light output, rad hard
Cerium fluoride	CeF <sub>3</sub>	310 340	0.005 0.027	0.12	6.16	low light output, radiation hard
GSO	Gd <sub>2</sub> SiO <sub>5</sub> (Ce doped)	440	0.24	0.056 (90%) 0.4 (10%)	6.71	Fast, rad tolerant
ҮАР	YAlO <sub>3</sub> (Ce doped)	440	0.47	0.027	5.37	Fast, good mechanical properties
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# **Organic scintillators** - hydrocarbon molecules

•Based on excited states of carbon atom, typically electron orbitals of benzene ring (C=C bonds)



quasi-free electrons confined to molecular perimeter (length l)

1-d Schrodinger equation  $\Rightarrow$  (x) = (x+l)

 $E_n = n^2 h^2 / 2me^2 l^2$ 

spectrum of energy levels

In practice more complex, vibrational states give fine structure range of singlet & triplet states gives both long and short time constants

## **Organic scintillator spectra**

### •Complex spectrum of energy levels

major S & P states accompanied by vibrational sub-levels -  $E \sim 0.16eV$ ionisation raises electron to excited state

 $S_3$ 

 $S_{2 S_{20}}$ 

 $S_1 \hspace{0.1 cm} {}_{S_{10}}$ 

 $S_0 S_{00}$ 

 $S_{13}$  ·

fast decay to S<sub>00</sub>

followed by radiative decay to ground states

= fluorescence ~nsec  $E_{S1-S2} \sim few eV$ or non-radiative decay S-P slow and less likely radiative decay P-S

phosphorescence ~msec

can also have "delayed fluorescence" from P state thermally excited to  $S_1$ 



singlet

22

triplet

P2

### **Organic scintillator characteristics**

•Solid base material (plastic) doped with fluor - but can be liquid scintillator inexpensive, low Z (primarily C, H, O)

•Primary fluor likely to be very short wavelength

not usually matched to available sensors

re-absorption by secondary fluor shifts light to longer, detectable wavelength

overlapping spectra required

Initial photon is absorbed within a few mm, then re-emitted

plastic doped with wavelength shifters converts far-UV light emission to convenient part of spectrum



can be also used to transport light - eg in fibre or plastic light guide
•multi-step process, including efficiency & attenuation

low light output cf inorganic scintillators, and non-linear

# **Examples of organic scintillators**

Primary fluor	peak wavelength nm	time constai ns	relative light nt output cf NaI	Originally dis materials like have produce tertiary syst	covered e anthra ed a wide ems	l in pure : Icene but e range o	natural chemists f binary and	
Napthalene	348	96	0.12					
Anthracene	440	30	0.5	Chemistry of	fluors	determin	es and	
p-terphenyl	440	5	0.25	time constants				
PBD	360	1.2						
Wavelength shifter			Typical commercial products (Nuclear Enterprises)					
POPOP	420	1.6		peak			Attenuation	
bis-MSB	420	1.2		wavelength	trise	tdecay	length	
BBQ	500				ns	ns	ст	
			NE110	434	1.0	3.0	400	
			NE104	406	0.6	1.8	120	
			NE108	535		~15		

#### Applications

fast detection but without energy measurement, Time of Flight astro-particle physics, environmental monitoring, nuclear detection

# **Light collection from scintillators**

•Primary and subsequent emission will be isotropic

very often require light to be collected on a area much smaller than scintillator on average, equal light intensity per face

make use of total internal reflection at surface to enhance collection at sensor



### **Scintillators - summary**

#### •Inorganic

based on crystals

important for accurate energy measurement and stopping power

### •Organic

molecular property of hydrocarbons important for speed and low cost

### •Long term behaviour

Both types of scintillator are damaged slowly by radiation inorganic - atomic displacement creates new band gap energy levels giving attenuation of light organic - breaking of chemical bonds alters chemistry reduction of light output and attenuation

# **Cerenkov** radiation



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27

## **Examples of Cerenkov radiators**

Radiator		n	$\theta_{max}$	$N_0 (cm^{-1})$		
			= 1	200 < < 750nm		
Но	ດວຣ	1 000035	0.48°	0.11		
Air	gas	1.000283	1.36°	0.94		
Isobutane	gas	1.001270	<b>2.89°</b>	4.3		
Aerogel	solid	1.025-1.075	12.7-21.5°	81-226		
Freon	liquid	1.233	<b>35.8°</b>	575		
Water	liquid	1.33	<b>41.2°</b>	729		
Quartz	solid	1.46	46.7°	892		
BGO	solid	2.15	62.3°	1319		

### **Exotics**

#### •Transition radiation

radiation emitted when charged particle crosses dielectric boundary signals in x-ray region (~ few keV) very weak radiation - multiple boundaries required to generate measurable signal but amplitude ~  $\gamma = 1/(1-\beta^2)^{1/2}$  particle ID at very high energy

#### •Bolometers

large fraction of ionisation energy does not appear as electrical signal in crystals, eg silicon, excites phonons in crystal = heat quantum of measurement = energy per phonon ~ meV (10<sup>-3</sup>eV!) potential for very high energy resolution measure change in T T =  $E_{deposit}/C$  C = heat capacity of sensor  $C \sim mass$  so need small sensor and low T (near OK) nevertheless, some good results  $E_{FWHM}$  = 17eV at 0.05K for 6keV x-ray •Superconducting sensors - several types two metal superconductors separated by thin insulator layer

under bias, QM tunneling of ionised excited states through insulator

 $\epsilon \sim meV$  gives potential for high resolution

# **Application: particle identification**

•A common requirement in nuclear and particle physics is to identify which type of particle is being observed

```
•stable neutral particles - , n
```

very different types of interaction so easy to distinguish- discuss later

•stable or long-lived charged particles: e<sup>-</sup>, p<sup>+</sup>, <sup>±</sup>, K<sup>±</sup>, d, He<sup>+</sup>, other ions typically momentum measurement is made by bending charged particle in B field Force = qvxB = mv<sup>2</sup>/r => r = qB/p if motion in plane perpendicular to B direction of bend indicates if charge is + or -

•p and charge are not enough to identify particle, need measurement of m or E  $E^2 = m^2 + p^2$  (c = 1 units , m = MeV/c<sup>2</sup>, E = MeV, p = MeV/c) Two common methods : Time of Flight & Cerenkov

### **Time of Flight**

•Simply measure time taken between two measurement points, separation L  $t_1 = L/v_1$   $t_2 = L/v_2$  1/ = E/p  $1+m^2/2p^2$  for  $p \gg m$  $t = t_1 - t_2 = (L/c)(1/(1-1)/2) = 3.3ns(1/(1-1)/2)$  for L = 1m Since ~ 1, good measurement accuracy required **30F**  $t = (L/2p^2c)(m_1^2 - m_2^2)$ 25 time of flight (ns) electron  $m_{e} = 0.511 \text{ MeV}/c^{2}$ 20 pi  $m = 140 \text{ MeV}/c^2$ K 15  $m_{\rm K} = 494 \ {\rm MeV}/{\rm c}^2$ proton 10  $m_{p} = 938 \text{ MeV}/\text{ }c^{2}$ 5 0 •Requirements 500 2000 1000 1500 fast scintillator with high photon output p (MeV/c)thick scintillator (~few cm) for maximum light signal fast response photodetector 31 g.hall@ic.ac.uk www.hep.ph.ic.ac.uk/~hallg/ 18 October, 2001

### **Cerenkov identification**

•cos = 1/n so > 1/n for light emission

•light output N =  $N_0 Lsin^2$  =  $N_0 L(1-1/2n^2)$ 

